Optical disc ICs

4-channel PWM driver for CD and MD players BH6511FS

The BH6511FS is an IC designed for CD and MD player motors and actuators, and has an internal 4-channel PWM driver, and a charge pump circuit that supplies the gate drive for the output stage power MOSFET. The power MOS-FET in the output stage assures low power consumption for applications.

Applications
CD and MD players

Features

- 1) Internal 4-channel power MOS H-bridge.
- Adaptable for PWM input.
- 3) Internal charge pump circuit to raise VG voltage.
- 4) Low ON resistance.
- 5) Low power consumption.
- 6) 32-pin SSOP-A compact package.

●Absolute maximum ratings (Ta=25℃)

Parameter	Symbol	Limits	Unit	
H-bridge supply voltage	VM	9	V	
Control circuit supply voltage	Voo	9	v	
Predriver supply voltage	VG (2pin)	12	v	
Driver output current	10 (CH1, CH3) 10 (CH2, CH4)	500 300*1	mA	
Power dissipation	Pd	850 * ²	mW	
Operating temperature	Topr	-30~85	ĉ	
Storage temperature	Tstg	-55~150	ĉ	

* 1. 500 msec.

*2. Reduced by 6.8 mW for each Increase in Ta of 1°C over 25°C.

Recommended operating conditions

Parameter	Symbol	Min.	Тур.	Max.	Unit	
H-bridge supply voltage	VM*	1.6	5.0	5.5	V	
Control circuit supply voltage	VDD	2.7	3.0	5.5	V	
Predriver supply voltage	VG (2pin)	VM+3.0	10	11.5	٧	
Ambient temperature	Та	35	25	85	ĉ	
Pulse input frequency	fin	-	176.4	200	kHz	

* Internal charge pump not used. When used, H-bridge supply voltage = 2.7-5.5 V.

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CHARGE PUMP & OSC

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Block diagram

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INTERFACE

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Optical Disc ICs

CD/CD-ROM Drivers (4 channels)

For CDs/CD-ROMs

Pin description

Pin No.	Pin name	Function	Pin No.	Pin name	Function
1	GND	Predrive ground	17	VDD	Predrive power supply
2	VG	Gate voltage supply	18	IN1R	Channel 1 reverse input
3	IN4R	Channel 4 reverse input	19	IN1F	Channel 1 forward input
4	IN4F	Channel 4 forward input	20	VM1	Power supply
5	VM4	Power supply	21	OUT1F	Channel 1 forward output
6	OUT4F	Channel 4 forward output	22	PGND1	Power ground
7	PGND4	Power ground	23	OUT1R	Channel 1 reverse outputd
8	OUT4R	Channel 4 reverse output	24	VM12	Power supply
9	VM34	Power supply	25	OUT2R	Channel 2 reverse output
10	OUT3R	Channel 3 reverse output	26	PGND2	Power ground
11	PGND3	Power ground	27	OUT2F	Channel 2 forward output
12	OUT3F	Channel 3 forward output	28	VM2	Power supply
13	VM3-	Power supply	29	IN2F	Channel 2 forward input
14	IN3F	Channel 3 forward input	30	IN2R	Channel 2 reverse input
15	IN3R	Channel 3 reverse input	31	CAPA+	Charge pump capacitor connection (positive)
16	PSB	Power cut	32	CAPA-	Charge pump capacitor connection (negative

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Pin equivalent circuit diagrams

VM34

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GND

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CAPA-

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VG

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Optical Disc ICs

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	Measurement Circuit	
H-bridge supply current		<u> </u>						
No input	IMST	_	320	380	μA	VDD=3V, VM=5V	Fig.3	
Control circuit supply current								
No input	IDD1	-	_	-1	μA		Fig.3	
Operating	IDD2	—	6	70	μA	IDD1/4-channel simultaneous drive	Fig.3	
Predriver supply voltage (cha	rge pump ou	itput)						
No input	VGST	8.8	9. 9 5	12	V		Fig.3	
Operating	VGA	7.9	8.5	11	V	4-channel simultaneous drive	Fig.3	
Logic input characteristics								
Input voltage, high level	VIH	Voo-0.6	_	-	V		Fig.3	
Input voltage, low level	VIL	—	-	0.6	٧		Fig.3	
Input current, high level	ΠΗ	-		1	μA		Fig.3	
Input current, low level	IIL	-1	—	_	μA		Fig.3	
Output ON registeries	RON1, 3	-	0.8	1.2	Ω	1.2 2.0	Sum of top and bottom ON resistance VM=2.5V, V∞=3V, VG=10V	Fig.3
Output ON resistance	RON2, 4	_	1.2	2.0			(VG is supplied externally)	rig.o
Output delay time	trise	-	0.2	1	μsec		Fig.3	
	TFALL	-	0.2	1	μsec		Fig.3	
Minimum input pulse width	tм in.	150	—		nsec	Output pulse width = 2/3 tmin. (minimum)	Fig.3	
Oscillator frequency	fosc	150	340	420	kHz	Pin 31 waveform monitor	Fig.3	

●Electrical characteristics (unless otherwise noted, Ta=25℃, V_M=5V, V_{DD}=3V, VG=internal charge pump output,

O Not designed for radiation resistance.

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Circuit operation

(1) PWM driver

The output stage is an H-bridge driver with four N-type FET circuits. Output PWM duty is changed according to input PWM duty. This pulse drives the load (direct PWM).

Driver truth table

PSB*	IN1~4F	IN1~4R	OUT1~3F	OUT1~3R	OUT4F	OUT4R
н	L	, L	L	L.	L	L
Н	L	Н	L	н	L	Н
н	н	L	н	L	L	L
н	н	н	L	L L	н	L
L	X	Х	L	L	L	L

 All outputs are L,L in the PSB mode, regardless of inputs. Even in this state, however, the charge pump circuit does not stop free-run oscillation.

(2) Charge pump

- A dedicated charge pump that supplies the drive voltage to the output stage H-bridge power MOS-FET.
- (3) Because the charge pump circuit doubles the voltage using pin 9 voltage as its reference, VG is not output unless VM is impressed on pin 9. Also, be sure to set the VM voltage to keep the charge pump voltage under the absolute maximum rating.
- (4) When supplying VG directly from an external source, rather than using the internal charge pump circuit, disconnect the capacitor between pins 31 and 32.
- (5) A charge pump capacitor between 0.01 and 0.1 µ F is recommended. Using one with a greater capacity will not significantly improve performance.

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BH6511FS

For CDs/CD-ROMs







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BH6511FS

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